

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

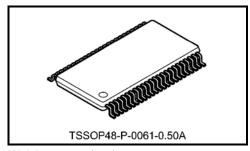
# TC74LCXR164245FT

#### 16-Bit Dual Supply Bus Transceiver with Series Resistor

The TC74LCXR164245FT is a dual supply, advanced high-speed CMOS 16-bit dual supply voltage interface bus transceiver fabricated with silicon gate CMOS technology.

Designed for use as an interface between a 5-V bus and a 3.3-V or 2.5-V bus in mixed 5-V/3.3-V or 2.5-V supply systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is intended for 2 way asynchronous communication between data busses. The direction of data transmission is determined by the level of the DIR input. The enable input  $(\overline{OE})$  can be used to disable the device so that the buses are effectively isolated. The B-port interfaces with the 5-V bus, the A-port with the 3.3-V or 2.5-V-bus.



Weight: 0.25 g (typ.)

The  $26-\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features (Note)

- Bidirectional interface between 5 V and 3.3 V or 2.5 V buses
- Wide operating temperature range: Topr = −40 to 125 °C (Note 1)
- 26-Ω series resistors on outputs
- High-speed:  $t_{pd} = 6.8 \text{ ns (max)}$

$$(V_{CCB} = 5.0 \pm 0.5 \text{ V/V}_{CCA} = 3.3 \pm 0.3 \text{ V}, \text{ Ta} = -40 \text{ to } 85^{\circ}\text{C})$$

- Low power dissipation:  $I_{CC} = 80 \mu A \text{ (max) (Ta} = -40 \text{ to } 85^{\circ}\text{C)}$
- Symmetrical output impedance:  $IOUTB = \pm 12 \text{ mA (min)}$

IOUTA = ±12 mA (min) (V<sub>CCB</sub> = 4.5V/V<sub>CCA</sub> = 3.0 V)

- Power-down protection is provided on all inputs and outputs.
- Allows A port and  $V_{CCA}$  to float simultaneously when  $\overline{OE}$  is "H"
- Latch-up performance: -500 mA
- Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input fixed by means of pull-up or pull-down resistors.

Note 1: For devices with the ordering part number ending in (\*KF. Topr = -40 °C to 85 °C for the other devices.

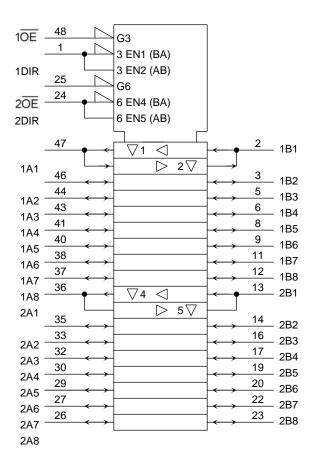
Start of commercial production 2020-01



#### Pin Assignment (top view)

#### 10E 1DIR 48 1B1 2 1A1 1B2 3 1A2 GND **GND** 1B3 5 1A3 1B4 6 1A4 43 V<sub>CCA</sub> (3.3 V) (5 V) VCCB 7 1B5 8 1A5 1B6 1A6 GND 10 **GND** 1B7 11 1A7 1B8 12 1A8 37 2B1 13 36 2A1 2B2 14 35 2A2 GND 15 **GND** 2B3 16 2A3 33 2B4 17 32 2A4 (5 V) V<sub>CCB</sub> 18 V<sub>CCA</sub> (3.3 V) 2B5 19 2A5 2B6 20 2A6 GND 21 GND 28 2B7 22 2A7 2B8 23 2A8 20E 2DIR 24

## **IEC Logic Symbol**





#### **Truth Table**

Inp	uts	Fun	ction	
1 <del>OE</del>	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs
L	L	Output	Input	A = B
L	Н	Input Output		B = A
Н	X	2	Z	

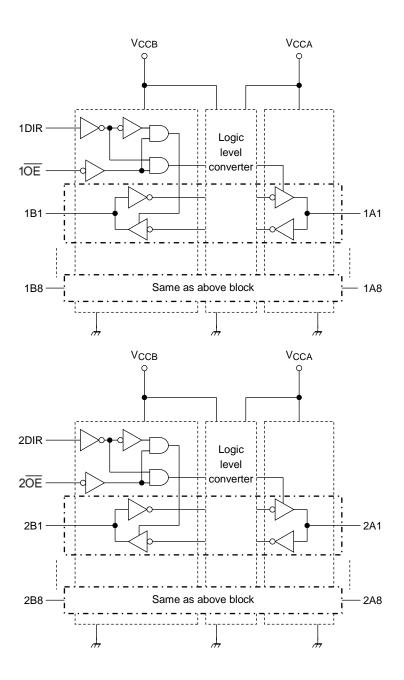
Inp	uts	Fun			
2 <del>OE</del>	2DIR	Bus 2A1-2A8	Bus 2B1-2B8	Outputs	
L	L	Output	Input	A = B	
L	Н	Input	Output	B=A	
Н	Х	2	7	Z	

X: Don't care

Z: High impedance



## **Block Diagram**





#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit	
Device complements (Note 4)	Vccb	-0.5 to 7.0	V	
Power supply voltage (Note 1)	VCCA	-0.5 to VCCB + 0.5	V	
DC input voltage (DIR, $\overline{\text{OE}}$ )	VIN	-0.5 to 7.0	V	
		-0.5 to 7.0 (Note 2)		
DO hua I/O valkana	VI/OB	-0.5 to V <sub>CCB</sub> + 0.5 (Note 3)	V	
DC bus I/O voltage		-0.5 to 7.0 (Note 2)	V	
	VI/OA	-0.5 to V <sub>CCA</sub> + 0.5 (Note 3)		
Input diode current	lık	-50	mA	
Output diode current	II/OK	±50 (Note 4)	mA	
DC output ourrent	I <sub>OUTB</sub>	±50	mA	
DC output current	IOUTA	±50	mA	
DC Vac/ground ourrent per guanty six	ICCB	±100	mA	
DC V <sub>CC</sub> /ground current per supply pin	ICCA	±100	ША	
Power dissipation	PD	400 (Note 5)	mW	
Storage temperature	T <sub>stg</sub>	-65 to 150	°C	

Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even Note: destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Don't supply a voltage to VCCA terminal when VCCB is in the off-state.
- Note 2: OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: VOUT < GND, VOUT > VCC
- Note 5: 400 mW in the range of T<sub>a</sub> = -40 to 85. From T<sub>a</sub> = 85 to 125 °C a derating factor of -6.25 mW/°C shall be applied until 150 mW.



#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Dower cumply voltage	Vccв	4.5 to 5.5	V
Power supply voltage	VCCA	2.3 to 3.6	V
Input voltage (DIR, $\overline{OE}$ )	VIN	0 to 5.5	٧
	Vivon	0 to 5.5 (Note 1)	
Due I/O wellenge	VI/OB	0 to VCCB (Note 2)	V
Bus I/O voltage	Vivo	0 to 5.5 (Note 1)	V
	VI/OA	0 to VCCA (Note 2)	
	Іоитв	±12 (Note 3)	
Output current	la	±12 (Note 4)	mA
	IOUTA	±4 (Note 5)	
Operating temperature	Topr	-40 to 125 (Note 6)	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 1: OFF state

Note 2: High or low state

Note 3: VCCB = 4.5 to 5.5 V

Note 4 VCCA = 3.0 to 3.6 V

Note 5 VCCA = 2.3 to 2.7 V

Note 6 For devices with the ordering part number ending in (\*KF. Topr = -40 °C to 85 °C for the other devices.

Note 7 VINB = 0.8 to 2.0 V, VCCB = 5.0 VVINA = 0.8 to 2.0 V, VCCA = 3.0 V



#### **Electrical Characteristics**

## DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Test (	Condition	V <sub>CCB</sub> (V)	V <sub>CCA</sub> (V)	Min	Max	Unit
	VIHB	DIR, $\overline{OE}$ , Bn		$5.0 \pm 0.5$	2.3 to 3.6	2.0	_	
H-level input voltage	Maria	Α			$2.5\pm0.2$	1.7	_	V
	VIHA	An		5.0 ± 0.5	$3.3 \pm 0.3$	2.0	_	
	VILB	DIR, OE, Bn		$5.0\pm0.5$	2.3 to 3.6	_	0.8	
L-level input voltage	\/	۸۵		$5.0\pm0.5$	$2.5 \pm 0.2$	_	0.7	V
	VILA	An		$5.0\pm0.5$	$3.3 \pm 0.3$		0.8	
	Vонв		IOHB = -100 μA	5.0 ± 0.5	2.3 to 3.6	VCCB - 0.2	١	
		VINA	IOHB = -12 mA	4.5	2.3 to 3.6	3.7		
H-level output voltage		= VIHA OR VILA VINB = VIHB OR VILB	ΙΟΗΑ = -100 μΑ	5.0 ± 0.5	2.3 to 3.6	VCCA - 0.2		V
	Vона	- VIND OI VILD	IOHA = -12 mA	$5.0\pm0.5$	3.0	2.2	_	
			IOHA = - 4 mA	$5.0\pm0.5$	2.3	1.8	_	
	Volb	VINA = VIHA OR VILA VINB = VIHB OR VILB	I <sub>OLB</sub> = 100 μA	$5.0\pm0.5$	2.3 to 3.6	_	0.2	0.7 0.2 V 0.8
			IOLB = 12 mA	4.5	2.3 to 3.6	_	0.7	
L-level output voltage	VOLA		$I_{OLA} = 100 \mu A$	$5.0\pm0.5$	2.3 to 3.6	_	0.2	
			I <sub>OLA</sub> = 12 mA	$5.0\pm0.5$	3.0	_	0.8	
			I <sub>OLA</sub> = 4 mA	$5.0\pm0.5$	2.3	_	0.6	
	I <sub>OZB</sub>	$V_{IN} = V_{IHB}$ or $V_{I/OB} = 0$ to 5.5		5.0 ± 0.5	2.3 to 3.6		±5.0	٨
3-state output OFF state current	IOZA	$V_{IN} = V_{IHB}$ or $V_{I/OA} = 0$ to 5.5		5.0 ± 0.5	2.3 to 3.6	_	±5.0	μΑ
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> (DIR, $\overline{\text{OE}}$ )	= 0 to 5.5 V	5.5	3.6	_	±5.0	μА
Power-off leakage current	loff	V <sub>INA</sub> /V <sub>INB</sub> = 5.5	5 V	0	0	_	10	μА
	ICCB1	$V_{I/OA} = Open, V_{\overline{OE}}$ = $V_{CCB}$ ,	•	5.5	Open	_	80	
Quiescent supply current	I <sub>CCB2</sub>	V <sub>INA</sub> = V <sub>CCA</sub> or V <sub>INB</sub> = V <sub>CCB</sub> or		5.5	3.6	_	80	μА
	ICCA	VINA = VCCA or GND VINB = VCCB or GND		5.5	3.6	_	50	
	Ісств	V <sub>INB</sub> = 3.4 V pe	r input	5.5	2.3 to 3.6		2.0	mA
	Ісста	VINA = VCCA -	0.6 V per input	$5.0\pm0.5$	3.6		500	μА



# DC Characteristics (Note) ((Unless otherwise specified, Ta = -40 to 125 °C)

Characteristics	Symbol	Test (	V <sub>CCB</sub> (V)	VCCA (V)	Min	Max	Unit	
	VIHB	DIR, $\overline{OE}$ , Bn		$5.0 \pm 0.5$	2.3 to 3.6	2.0	_	
H-level input voltage	.,			$5.0 \pm 0.5$	$2.5\pm0.2$	1.7	_	V
	VIHA	An		5.0 ± 0.5	$3.3 \pm 0.3$	2.0	_	
	V <sub>ILB</sub>	DIR, OE, Bn		$5.0 \pm 0.5$	2.3 to 3.6		0.8	
L-level input voltage	Maria	Λ		$5.0 \pm 0.5$	$2.5\pm0.2$	_	0.7	V
	VILA	An		5.0 ± 0.5	$3.3 \pm 0.3$	_	0.8	
	Vонв		I <sub>OHB</sub> = -100 μA	5.0 ± 0.5	2.3 to 3.6	VCCB - 0.2	_	
		VINA	$I_{OHB} = -12 \text{ mA}$	4.5	2.3 to 3.6	3.3	_	
H-level output voltage		= VIHA OR VILA VINB = VIHB OR VILB	ΙΟΗΑ = -100 μΑ	5.0 ± 0.5	2.3 to 3.6	V <sub>CCA</sub> - 0.2		V
	Vона	- VIND OI VILD	IOHA = -12 mA	$5.0\pm0.5$	3.0	1.9	_	
			IOHA = - 4 mA	$5.0\pm0.5$	2.3	1.55	_	
	Volb	VINA = VIHA OR VILA VINB = VIHB OR VILB	IOLB = 100 μA	$5.0\pm0.5$	2.3 to 3.6	_	0.2	0.9 0.2 V
			I <sub>OLB</sub> = 12 mA	4.5	2.3 to 3.6	_	0.9	
L-level output voltage	VOLA		I <sub>OLA</sub> = 100 μA	$5.0\pm0.5$	2.3 to 3.6	_	0.2	
			I <sub>OLA</sub> = 12 mA	$5.0\pm0.5$	3.0	_	1.1	
			IOLA = 4 mA	$5.0\pm0.5$	2.3	_	1.0	
2 state output OFF state outront	I <sub>OZB</sub>	$V_{IN} = V_{IHB}$ or $V_{I/OB} = 0$ to 5.5		5.0 ± 0.5	2.3 to 3.6	_	±20.0	^
3-state output OFF state current	I <sub>OZA</sub>	$V_{IN} = V_{IHB}$ or $V_{I/OA} = 0$ to 5.5		5.0 ± 0.5	2.3 to 3.6	_	±20.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> (DIR, $\overline{\text{OE}}$ )	= 0 to 5.5 V	5.5	3.6	_	±20.0	μА
Power-off leakage current	loff	VINA/VINB = 5.5	5 V	0	0	_	40	μА
	ICCB1	$V_{I/OA} = Open, \ V_{\overline{OE}} = V_{CCB},$		5.5	Open	_	320	
Quiescent supply current	I <sub>CCB2</sub>	V <sub>INA</sub> = V <sub>CCA</sub> or V <sub>INB</sub> = V <sub>CCB</sub> or		5.5	3.6	_	320	μΑ
	ICCA	V <sub>INA</sub> = V <sub>CCA</sub> or V <sub>INB</sub> = V <sub>CCB</sub> or		5.5	3.6	_	200	
	ICCTB	V <sub>INB</sub> = 3.4 V pe	r input	5.5	2.3 to 3.6	_	2.0	mA
	ICCTA	VINA = VCCA -	0.6 V per input	$5.0\pm0.5$	3.6		5.0	mA

Note: For devices with the ordering part number ending in (\*KF. Topr = -40  $^{\circ}$ C to 85  $^{\circ}$ C for the other devices.

2020-01-31



#### **AC Characteristics**

(Unless otherwise specified, Ta = -40 to 85 °C, input:  $t_f = t_f = 2.5$  ns,  $R_L = 500 \Omega$ )

#### $V_{CCA}=3.3\pm0.3~V$

Characteristics	Symbol	Test Condition	CL (pF)	VCCB (V)	Min	Max	Unit
Propagation delay time $(Bn \to An)$	t <sub>pLH</sub>		50	5.0 ± 0.5	1.0	6.8	
3-state output enable time ( OE → An)	t <sub>pZL</sub> t <sub>pZH</sub>	Input: Bn Output: An (DIR = "L")	50	5.0 ± 0.5	1.0	10.0	ns
3-state output disable time ( OE → An)	t <sub>pLZ</sub>		50	5.0 ± 0.5	1.0	9.5	
Propagation delay time (An → Bn)	t <sub>pLH</sub>		50	5.0 ± 0.5	1.0	6.8	
3-state output enable time ( OE → Bn)	t <sub>pZL</sub> t <sub>pZH</sub>	Input: An Output: Bn (DIR = "H")	50	5.0 ± 0.5	1.0	10.0	ns
3-state output disable time ( OE → Bn)	t <sub>pLZ</sub> t <sub>pHZ</sub>		50	5.0 ± 0.5	1.0	9.5	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note1)	50	5.0 ± 0.5	_	1.0	ns

Note1 Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

#### $V_{CCA}=2.5\pm0.2\;V$

Characteristics	Symbol	Test Condition	CL (pF)	VCCB (V)	Min	Max	Unit
Propagation delay time $(Bn \to An)$	t <sub>PLH</sub>		30	5.0 ± 0.5	1.0	9.0	
3-state output enable time ( OE → An)	t <sub>pZL</sub> t <sub>pZH</sub>	Input: Bn Output: An (DIR = "L")	30	5.0 ± 0.5	1.0	12.5	ns
3-state output disable time $(\overline{OE} \rightarrow An)$	t <sub>pLZ</sub> t <sub>pHZ</sub>		30	5.0 ± 0.5	1.0	11.5	
Propagation delay time $(An \to Bn)$	t <sub>pLH</sub> t <sub>pHL</sub>		50	5.0 ± 0.5	1.0	10.0	
3-state output enable time ( OE → Bn)	t <sub>pZL</sub> t <sub>pZH</sub>	Input: An Output: Bn (DIR = "H")	50	5.0 ± 0.5	1.0	12.5	ns
3-state output disable time ( OE → Bn)	t <sub>pLZ</sub> t <sub>pHZ</sub>		50	5.0 ± 0.5	1.0	11.5	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note1)	30 or 50	5.0 ± 0.5	l	1.0	ns

Note1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



#### **AC Characteristics (Note)**

(Unless otherwise specified, Ta = -40 to 125 °C, input:  $t_r = t_f = 2.5$  ns,  $R_L = 500 \Omega$ )

#### $V_{CCA}=3.3\pm0.3~V$

Characteristics	Symbol	Test Condition	CL (pF)	VCCB (V)	Min	Max	Unit
Propagation delay time $(Bn \to An)$	t <sub>pLH</sub> t <sub>pHL</sub>		50	5.0 ± 0.5	1.0	7.3	
3-state output enable time $(\overline{OE} \rightarrow An)$	t <sub>pZL</sub> t <sub>pZH</sub>	Input: Bn Output: An (DIR = "L")	50	5.0 ± 0.5	1.0	10.7	ns
3-state output disable time $(\overline{OE} \rightarrow An)$	t <sub>pLZ</sub> t <sub>pHZ</sub>		50	5.0 ± 0.5	1.0	10.2	
Propagation delay time $(\mathrm{An} \to \mathrm{Bn})$	t <sub>pLH</sub> t <sub>pHL</sub>		50	5.0 ± 0.5	1.0	7.3	
3-state output enable time $(\overline{OE} \rightarrow Bn)$	t <sub>pZL</sub> t <sub>pZH</sub>	Input: An Output: Bn (DIR = "H")	50	5.0 ± 0.5	1.0	10.7	ns
3-state output disable time $(\overline{OE} \rightarrow Bn)$	t <sub>pLZ</sub> t <sub>pHZ</sub>		50	5.0 ± 0.5	1.0	10.2	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note1)	50	5.0 ± 0.5	_	1.0	ns

Note: For devices with the ordering part number ending in (\*KF. Topr = -40 °C to 85 °C for the other devices.

Note1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

#### $V_{CCA}=2.5\pm0.2\;V$

Characteristics	Symbol	Test Condition	CL (pF)	V <sub>CCB</sub> (V)	Min	Max	Unit
Propagation delay time $(Bn \to An)$	t <sub>pLH</sub> t <sub>pHL</sub>		30	5.0 ± 0.5	1.0	9.7	
3-state output enable time ( OE → An)	t <sub>p</sub> ZL t <sub>p</sub> ZH	Input: Bn Output: An (DIR = "L")	30	5.0 ± 0.5	1.0	13.4	ns
3-state output disable time $(\overline{OE} \rightarrow An)$	t <sub>pLZ</sub> t <sub>pHZ</sub>		30	5.0 ± 0.5	1.0	12.4	
Propagation delay time $(An \to Bn)$	t <sub>pLH</sub> t <sub>pHL</sub>		50	5.0 ± 0.5	1.0	10.7	
3-state output enable time ( OE → Bn)	t <sub>p</sub> ZL t <sub>p</sub> ZH	Input: An Output: Bn (DIR = "H")	50	5.0 ± 0.5	1.0	13.4	ns
3-state output disable time ( OE → Bn)	t <sub>pLZ</sub>		50	5.0 ± 0.5	1.0	12.4	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note1)	30 or 50	5.0 ± 0.5	_	1.0	ns

Note: For devices with the ordering part number ending in (\*KF. Topr = -40 °C to 85 °C for the other devices.

Note1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)



## **Capacitive Characteristics (Ta = 25°C)**

## $V_{CCB} = 5.0 V$

Characteristics		Symbol	Test Circuit	Test Condition	VCCA (V)	Тур.	Unit	
Input capacitance		CIN	_	DIR, OE	2.5, 3.3	7	pF	
Output capacitance		C <sub>I/O</sub>	_	An, Bn	2.5, 3.3	8	pF	
		C :		A ⇒ B (DIR = "H")	2.5, 3.3	2	۰,۲	
Power dissipation capacitance		C <sub>PDA</sub>		$B \Rightarrow A (DIR = "L")$	2.5, 3.3	26	pF	
	(Note)	C		A ⇒ B (DIR = "H")	2.5, 3.3	36	۰,۲	
			C <sub>PDB</sub>		$B \Rightarrow A (DIR = "L")$	2.5, 3.3	4	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

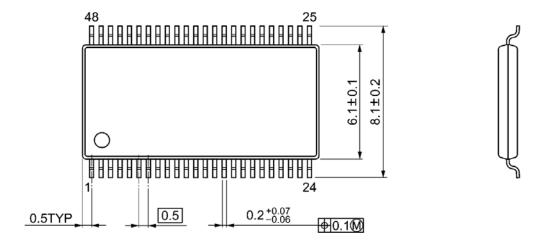
Average operating current can be obtained by the equation:

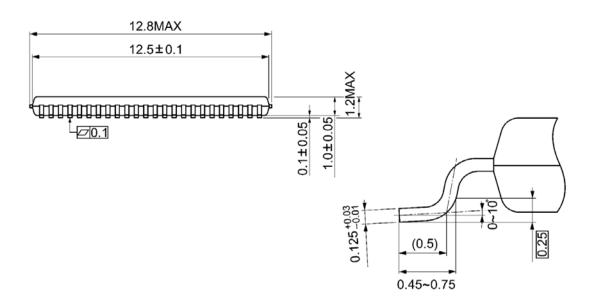
ICC (opr) = CPD·VCC·fIN + ICC/16 (per bit)



## **Package Dimensions**

TSSOP48-P-0061-0.50A Unit: mm





Weight: 0.25 g (typ.)



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